NSN 5961-01-359-7595

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-7595 **Inclosure Material:** Ceramic **Overall Length:** Between 0.815 inches and 0.835 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Height:** Between 0.240 inches and 0.270 inches **Overall Width:** Between 0.685 inches and 0.695 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Reverse polarity **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 150.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes source cutoff current preset all semiconductor device diode and 150.00 amperes forward current, average preset all semiconductor device diode **Special Features:** Common anode; all semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 02750-kkk327 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No